

DMD 0.7 XGA 12° DDR DMD Discovery™

This data sheet describes the 0.7XGA 12° DDR DMD Discovery™.



Revision History				
Rev	ECR	Date	Sections	Summary of Changes
A	2033877	01/21/2002	All	Initial Release for Discovery™ applications
			Table 3	updated Differential Temperature
			Table 4	updated VCC2
			Table 4	updated ILLir
			Error! Reference source not found.7	updated DCLK minimum frequency
			Error! Reference source not found.9	updated Thermal Resistance
			Table 11	added detailed Note 1 for Optical / System IQ
			Error! Reference source not found.7	removed maximum pulse widths (Tw)
			Figure 3	added DMD Marking Locations
B	2048988	7/29/2004	Table 1	added DMD Part Number table & image quality nomenclature
			Error! Reference source not found.6	removed minimum capacitance for MBRST
			Figure 1	added block diagram and architecture description
			Tables 2 & 3	changed MBRST, VCC2, & CMD pin names
			Table 3	added incident power and energy
			Table 3	modified Note 6
			Table 3	added Note 4 on VCC2 protection diode
			Table 4	added T _{RST} , ILL _{UV} , Note 2
			Tables 6 & 7	deleted timing diagram
			Table 10	removed obsolete Active Area Fill Factor
C	2048883	09/28/2004	Revisions	created Revision History table
			Table 2	added reference to Pull-Down Resistors for MBRST(15:0)
			Page 21	added reference to JESD22-A114-B ESD Sensitivity HBM
			Table 14	added DMD ESD Protection Limits
			Table 4	added Note 5 for Operating Temperature Minimum
			Table 4	Note 3 changed from 1.32ns to 2.5ns for Rise and Fall times
			Table 1	modified image quality definition
			Table 4	changed UV maximums; modified Note 2; added Notes 5&6
			Error! Reference source not found.7	changed from 1.32ns to 2.5ns max rise & fall times
D	2054635	02/14/2005	Title Page	updated revision to D and updated date to February 2005
			Revisions	added ECR numbers to Revision History table
			Footers	updated year to 2005 and updated revision to D
			Footers	added Page Numbers to several pages where it was missing
			Headers	added document Title to several pages where it was missing
			All Tables	corrected Captions and Cross Reference links
			All Figures	corrected Captions and Cross Reference links

			Table 1 Table 3 Table 3 Table 3 Table 4 Table 4 Error! Reference source not found.5 Page 21	updated Mechanical ICD drawing number for UV part 1076-714c added Differential Temperature maximum for UV Application added ILL _{UV330} , ILL _{UV340} , ILL _{UV350} , and ILL _{UV400} added Note 6 and renamed original Note 6 to Note 7 replaced “Simulation” with “Tester” in Note 3 added ILL _{peak} corrected sign reference direction for loh (–)and lol (+) replaced “according to” with “and are tested in accordance with”
E	2055953	3/28/2005	Title Page	updated revision to E and updated date to March 2005
			Table 10	modified Note 3
			Table 10	added visible window transmittance below 420nm & Note 4
			Table 10	added UV window transmittance & Note 5
F	2061197	08/22/2005	Title Page	updated revision to F and updated date to August 2005
			Table 3	deleted UV information and renumbered Notes
			Table 4	deleted UV information and renumbered Notes
			Table 10	moved UV window transmittance from Min to Nom

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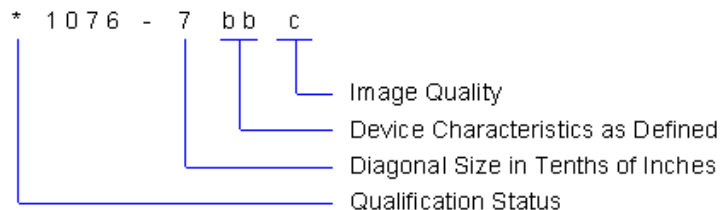
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Table 1. Product Description		
DMD Part #	Mechanical ICD	Description
*1076-729c	2503606	0.7 inch diagonal spatial light modulator of aluminum micro-mirrors. Pixel array size is 1024 X 768 in square grid pixel arrangement. Data is clocked into the DMD on both the rising and falling edges of DCLK. This is referred to as Double Data Rate (DDR). Pixel architecture is XB. Window is optimized for visible (400nm – 700nm) wavelengths.
*1076-740c	2503606	0.7 inch diagonal spatial light modulator of aluminum micro-mirrors. Pixel array size is 1024 X 768 in square grid pixel arrangement. Data is clocked into the DMD on both the rising and falling edges of DCLK. This is referred to as Double Data Rate (DDR). Pixel architecture is FTP. Window is optimized for visible (400nm – 700nm) wavelengths.
*1076-746c	2503606	0.7 inch diagonal spatial light modulator of aluminum micro-mirrors. Pixel array size is 1024 X 768 in square grid pixel arrangement. Data is clocked into the DMD on both the rising and falling edges of DCLK. This is referred to as Double Data Rate (DDR). Pixel architecture is FTP. Window is optimized for near infrared (900nm – 2000nm) wavelengths.
*1076-714c	2506435	0.7 inch diagonal spatial light modulator of aluminum micro-mirrors. Pixel array size is 1024 X 768 in square grid pixel arrangement. Data is clocked into the DMD on both the rising and falling edges of DCLK. This is referred to as Double Data Rate (DDR). Pixel architecture is FTP. Process and window are optimized for near ultraviolet (350nm – 450nm) wavelengths.

Part number description:



Qualification status nomenclature:

X – TMX – Experimental
P – TMP – Pre-production
S – TMS – Qualified

Image quality nomenclature:

*1076-xxx8: <5 defective mirrors in active area, <2 defective mirrors in POM (**Error! Reference source not found.**), no adjacent defective mirrors, no defective mirrors stuck in the “on” position (Figure 4), screened for window blemishes.

*1076-xxx4: Same as -xxx8, but not screened for window blemishes.

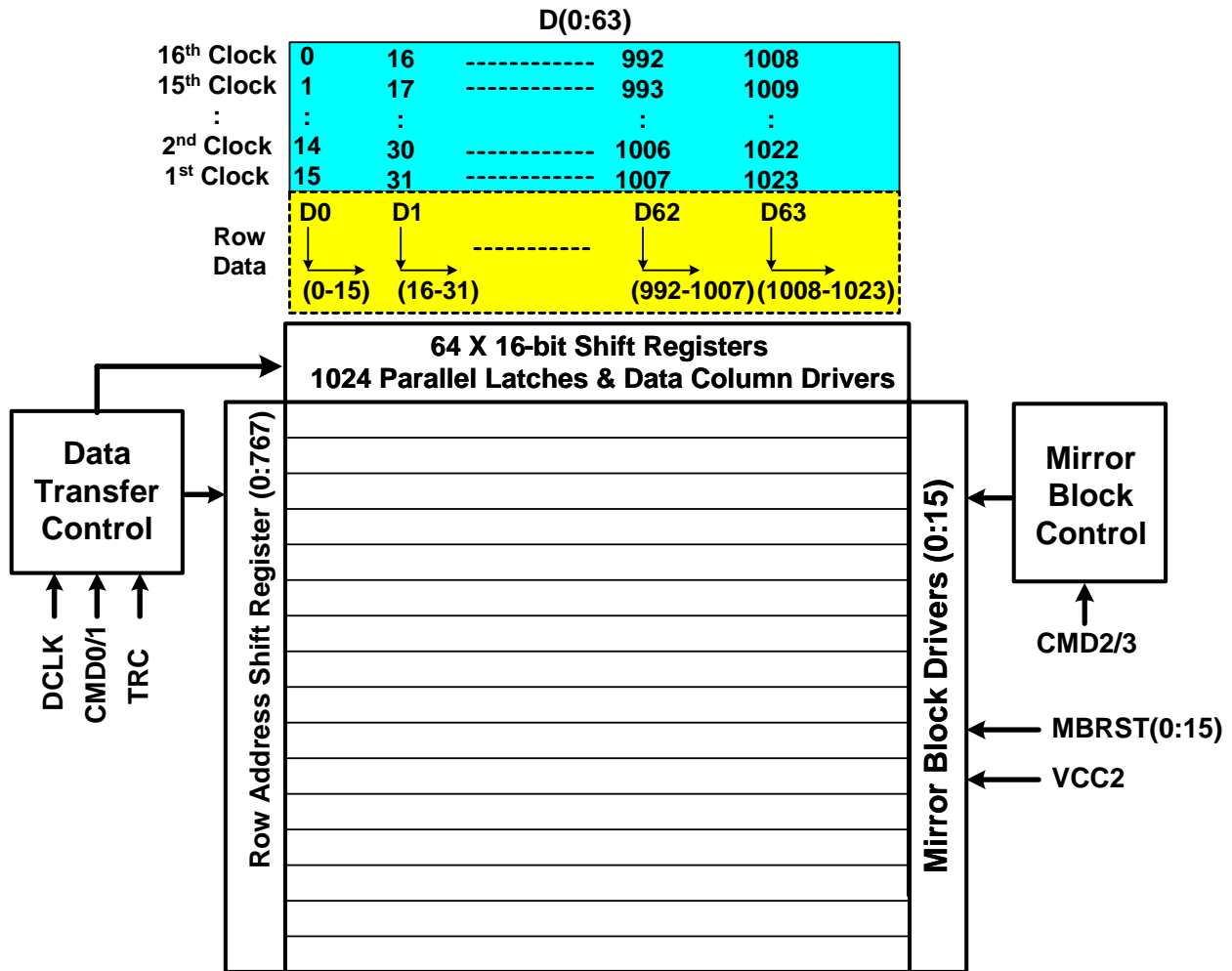


Figure 1. Functional Block Diagram

DMD Architecture

A functional block diagram is shown in Figure 1. Binary data is loaded one row at a time via the 64-bit data bus. The row address shift register determines which of the 768 rows is addressed. For each row the data for mirrors 15, 31, 47...1023 is loaded first and mirrors 0, 16, 32...1008 last. The DMD mirrors are grouped into 16 individually controlled blocks, with each block containing 48 rows of 1024 mirrors.

Table 2. I/O Pin Descriptions		
Pin Name	Description	I/O
D(0:63)	<ul style="list-style-type: none"> Data Bus Pin has an internal pull-down transistor circuit 	I
DCLK	<ul style="list-style-type: none"> Data Clock 	I
CMD (0:3)	<ul style="list-style-type: none"> Data and Mirror Control Signals 	I
TRC	<ul style="list-style-type: none"> Toggle Rate Control 	I
MBRST(0:15)	<ul style="list-style-type: none"> Non-logic compatible Mirror Bias/Reset inputs Connected directly to the Array of Pixel Mirrors Used to Hold or Release the Pixel Mirrors Bond pads connect to an internal pull-down resistor 	I
TP (65:67)	<ul style="list-style-type: none"> Test points (not used in normal operation) 	O
EVCC	<ul style="list-style-type: none"> Pre-charge voltage during SRAM read test Connect to VSS (GND) during normal operation 	PWR
VCC2	<ul style="list-style-type: none"> Mirror Electrode Stepped High Voltage 	PWR
VCC	<ul style="list-style-type: none"> Power Supply for CMOS logic 	PWR
VSS (GND)	<ul style="list-style-type: none"> Logic Ground / Common Return for all Power 	PWR

Table 3. Absolute Maximum Ratings Note 1				
Parameters		Min	Max	Units
Logic Supply voltage: VCC	Note 2	−0.5	4	VDC
Mirror Electrode voltage: VCC2	Note 2 Note 4	−0.5	8	VDC
Input voltage: MBRST(0:15)	Note 2	−28	28	V
Input voltage: other inputs	Note 2 Note 3	−0.5	VCC + 0.3	VDC
Operating Temperature:	Note 5			
<ul style="list-style-type: none"> Reverence location 1,2, & 3 in Figure 2 	Note 7	10	65	°C
Differential Temperature:				
<ul style="list-style-type: none"> Location 1 minus Location 3 in Figure 2 Location 2 minus Location 3 in Figure 2 			10 10	°C °C
Differential Temperature – UV Application:				
<ul style="list-style-type: none"> Location 1 minus Location 3 in Figure 2 Location 2 minus Location 3 in Figure 2 	Note 6		5 5	°C °C
Storage Temperature (non-operating):				
<ul style="list-style-type: none"> Reference Locations 1, 2, and 3 in Figure 2 		−40	80	°C
ILL _{UV350} Illumination, wavelength < 350nm	Note 6			
Operating Relative Humidity (non-condensing)		0	95	%
Storage Relative Humidity (non-condensing)		0	95	%

Note 1:

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the DMD. This is a stress rating only and functional operation of the DMD at these or any other conditions beyond those indicated in the “Recommended Operating Conditions” section of this product spec is not implied. Exposure to absolute maximum rated conditions for extend periods may affect device reliability.

Note 2:

All voltage values are with respect to GND (VSS).

Note 3:

Excludes reset lines MBRST(15:0)

Note 4:

It is critical to control EMI, voltage spikes, ripple and any other voltage variations that could lead to exceeding maximum VCC2 voltages. TI therefore recommends the installation of a zener diode on the VCC2 line as close as possible to the DMD. A suggested diode is the Vishay BZD27C8V2P. An equivalent or better 8.2v zener diode capable of dissipating the full load of the DAD1000 ASIC is recommended. TI also recommends that the user pay close attention to Electro-Static Discharge (ESD) concerns as the DMD is an ESD Sensitive device.

Note 5:

The DMD can be operated between 0°C and 10°C at power-up for a maximum period of 10 minutes without damage.

Note 6:

UV-optimized DMDs must be carefully controlled in terms of manufacturing process and illumination power spectral content. Usage below 350nm will rapidly degrade lifetime.

Note 7:

Active Array Temperature cannot be measured directly. therefore it must be computed analytically from measurement points on the outside of the package, the package thermal resistance, the electrical power, and the illumination heat load. The relationship between array temperature and the reference ceramic temperature is provided by the following equations.

$$T_{\text{array}} = T_{\text{ceramic}} + (Q_{\text{array}} \bullet (R_{\text{array-to-ceramic}}))$$

$$Q_{\text{array}} = (0.35 \bullet P_i) + 0.37$$

Where,

T_{array} = computed array temperature (°C)

T_{ceramic} = measured ceramic temperature (°C)

Q_{array} = Total DMD array power (electrical + absorbed) (watts)

$R_{\text{array-to-ceramic}}$ = DMD package thermal resistance from array to outside ceramic (°C/watt)

P_i = incident illumination power (watts)

The electrical power dissipation of the DMD is variable and depends on the voltages, data rates and operating frequencies. A nominal power dissipation to use when calculating array temperature is **0.37 Watts**. The absorbed power from the illumination source is variable and depends on the operating state of the mirrors and the intensity of the light source. The absorption constant **0.35** assumes nominal operation with all illumination power falling on the active array. For an illumination distribution of 83.7% on the active array, 11.9% on the array border, and 4.4 % on the window aperture, absorption of **0.42** should be used. A system aperture may be required to limit power incident on the package aperture since this area absorbs much more efficiently than the array.

Sample Calculation:

Incident illumination power = 20 watts

$T_{\text{ceramic}} = 40.0 \text{ C}$

$Q_{\text{array}} = (0.35 \bullet 20) + 0.37 = 7.37 \text{ watts}$

$T_{\text{array}} = 40.0 \text{ °C} + (7.37 \text{ watts} \bullet 0.9 \text{ °C/watt}) = 46.6 \text{ °C}$

For the maximum P_i calculation used in Table 3, T_{ceramic} is calculated from

$$T_{\text{ceramic}} = T_{\text{ambient}} + (Q_{\text{array}} \bullet R_{\text{ceramic-to-ambient}})$$

assuming a liquid cooled heat sink with $R_{\text{ceramic-to-ambient}} = 1.5 \text{ C/watt}$. Substituting an air-cooled heat sink would add an additional 3–5 C/watt, thereby severely limiting the allowed incident power.

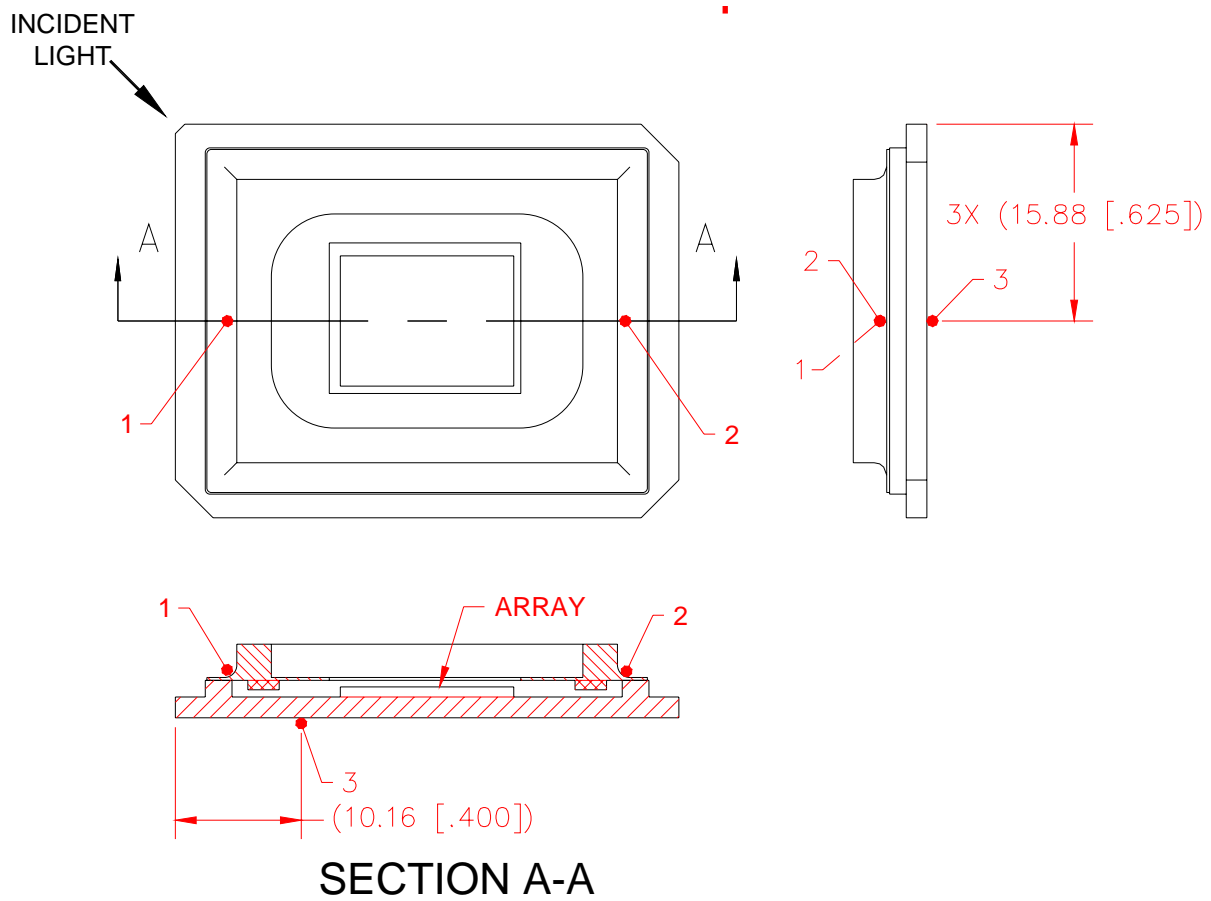


Figure 2. Thermocouple Locations

Table 4. Recommended Operating Conditions

Parameters			Min	Nom	Max	Units
VCC	Logic power supply voltage		3.0	3.3	3.6	V
VCC2	Mirror electrode voltage		7.25	7.5	7.75	V
V _{MBRST}	Mirror Bias / Reset voltage		-27		26.5	V
V _{IHD}	Dynamic high level input voltage	Note 3 Note 4	2.3		2.7	V
V _{IH}	Static high level input voltage	Note 3	1.7		VCC + 0.3	V
V _{IL}	Low level input voltage	Note 3	-0.3		0.7	V
I _{OH}	High level output current @ V _{oh} = 2.4v				-27	mA
I _{OL}	Low level output current @ V _{ol} = 0.4v				20	mA
T _C	Operating case temperature	Note 1	25		45	°C
ILL _{UV}	Illumination, wavelength < 400 nm	Note 2			0.68	mW/cm ²
ILL _{IR}	Illumination, wavelength > 800nm	Note 5			10	mW/cm ²
T _{RST}	Time between mirror resets on any given mirror block	Note 6			10	sec

Note 1:

Operating case temperature limits apply to the Array and to Locations 1, 2, & 3 referenced in Figure 2.

Note 2:

UV-optimized DMDs must be carefully controlled in terms of manufacturing process and illumination power spectral content. Usage below 350nm will rapidly degrade lifetime.

Note 3:

Tester Conditions for V_{IHD} V_{IH} V_{IL}:

Frequency = 60MHz

Maximum Rise/Fall Time = 2.5ns @ (20% – 80%)

Note 4:

V_{IHD} min/max range is required to guarantee component set set-up & hold specifications, using the conditions in Note 3.

Note 5:

DMDs optimized for near infrared (IR) illumination are considered experimental at this time. While there is no known DMD damage from infrared illumination, there have been no extensive lifetime studies above 800nm.

Note 6:

DMD mirrors are continuously reset when used in projectors. While leaving the mirrors landed for extended periods of time causes no known damage, there have been no extensive lifetime studies under these conditions.

DMD Marking Locations

The device marking is shown in Figure 3. The marking will include both human-readable information and a 2-dimensional matrix code. The human-readable information is described in Figure 3: The 2-dimensional matrix code is an alpha-numeric character string that contains the DMD part number, Part 1 of Serial Number, and Part 2 of Serial Number (example *1076-7bbc GHXXXXX LLLLLLM). The first character of the DMD Serial Number (part 1) is the manufacturing year. The second character of the DMD Serial Number (part 1) is the manufacturing month. The last character of the DMD Serial Number (part 2) is the bias voltage bin letter.

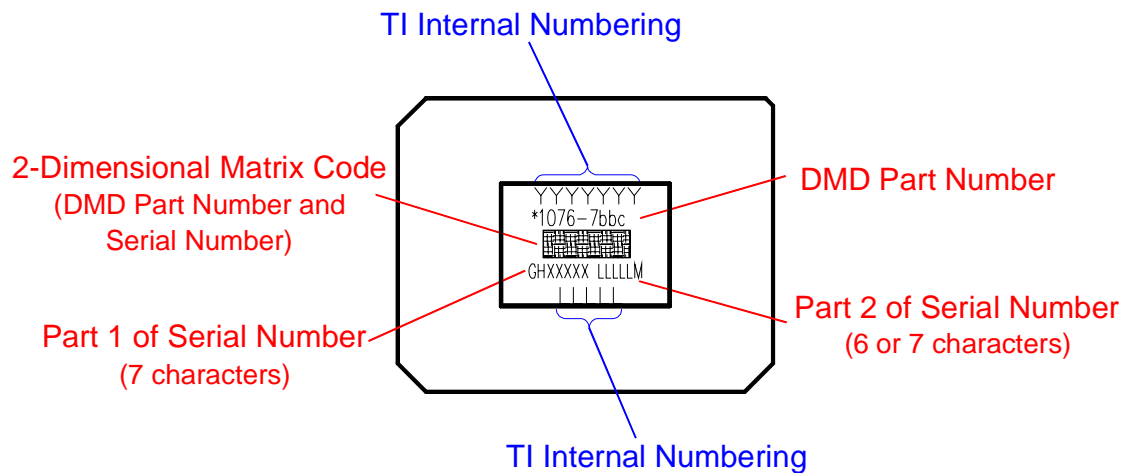


Figure 3. DMD Marking Locations

Table 5. Electrical Characteristics For Recommended Operating Conditions						
Parameters			Test Condition	Min	Max	Units
V _{OH}	High level output voltage		VCC = 3V I _{OH} = -27mA	2.4		V
V _{OL}	Low level output voltage		VCC = 3.6V I _{OL} = 20mA		0.4	V
I _{OZ}	Output high impedance current		VCC = 3.6V		10	uA
I _{IL}	Low level input current		VCC = 3.6V V _I = 0 to VCC		-5	uA
I _{IH}	High level input current		VCC = 3.6V V _I = VCC to 0		5	uA
I _{CC}	ICC current	Note 1	VCC = 3.6V		400	mA
I _{CC2}	ICC2 current	Note 1	VCC2 = 7.8V		15	mA
	Electrical input power				1.6	W

Note 1:

I_{CC} and I_{CC2} estimates are based upon the following test conditions:

- VCC = 3.6v
- VCC2 = 7.8v
- f = 60MHz
- Temp = 27C
- alternating checkerboard pattern & inverse checkerboard pattern

Table 6. Capacitance at Recommended Operating Conditions				
Parameters		Test Condition	Max	Units
C _I	Input Capacitance	f = 1MHz	10	pf
C _O	Output Capacitance	f = 1MHz	10	pf
C _{IM}	MBRST(15:0) Input Capacitance	f = 1MHz 1024 x 768 array all inputs interconnected	300	pf

Table 7. Critical Timing					
Parameter		Min	Typ	Max	Units
Ts	Setup time: DATA, TRC, CMD(0:1) before rising or falling edge of DCLK	1.5			ns
Th	Hold time: DATA, TRC, CMD(0:1) after rising or falling edge of DCLK	1.5			ns
Tw	Pulse Width high or low: DCLK	6.67			ns
Tr	Rise time (20% – 80%): DCLK, DATA, TRC Note 1			2.5	ns
Tr	Rise time (20% – 80%): CMD (0:2) Note 1			2.5	ns
Tr	Fall time (20% – 80%): DCLK, DATA, TRC Note 1			2.5	ns
Tr	Fall time (20% – 80%): CMD (0:2) Note 1			2.5	ns

Note 1: Max values to be used when operated at max frequency (Tw min).

Table 8. Physical Parameters					
Parameter		Min	Nom	Max	Units
Number of Columns			1024		
Number of Rows			768		
Mirror (Pixel) Pitch			13.68		um
Total Width of Active Mirror Array • 1024 pixels			14.008		mm
Total Height of Active Mirror Array • 768 pixels			10.506		mm
Active Array Border	Note 1		POM		
Active Array Border Size			6		mirrors/side

Note 1:

The structure and qualities of the border around the active array includes a band of partially functional mirrors called the “pond of mirrors” (POM). These mirrors are structurally and/or electrically prevented from tilting toward the bright or “on” state but still require an electrical bias to tilt toward “off.”

Table 9. Thermal Parameters					
Parameter		Min	Nom	Max	Unit
Thermal Resistance					
• Active area to case	Note 1			0.9	°C/W

Note 1:

The DMD is designed to conduct absorbed and dissipated heat to the back of the package where it can be removed by an appropriate heat sink. The heat sink and cooling system must be capable of maintaining the package within the specified operational temperatures.

The total heat load on the DMD is largely driven by the incident light absorbed by the active area; although other contributions include light energy absorbed by the window aperture and electrical power dissipation of the array.

Optical systems should be designed to minimize the light energy falling outside the window clear aperture since any additional thermal load in this area can significantly degrade the reliability of the device.

Table 10. Optical Parameters					
Parameter		Min	Nom	Max	Unit
Mirror Tilt – half angle					
• Variation device to device	Note 1	11	12	13	Degrees
Axis of Rotation – Lower Right to Upper Left					
• Variation device to device	Figure 4	44	45	46	Degrees
Active Area Fill Factor (by design)			88		%
Mirror Metal Specular Reflectivity (420nm – 700nm)			89.4		%
DMD Efficiency (420nm – 700nm, visible window)	Note 2		68		%
Window Refractive Index @ 545nm – Type A			1.487		
Window Transmittance (visible window) measured @ 420nm – 680nm including AR coating	Note 3	97			%
Window Transmittance (visible window) measured @ 350 – 420nm including AR coating	Note 4		TBD		
Window Transmittance (UV window) measured @ 350-450nm including AR coating	Note 5		98		%
Window Flatness @ 632.8nm spherical power / irregularity (astigmatism, etc)				4 / 2	fringes

Note 1: Mirror Tilt

Limits on variability of mirror tilt half angle are critical in the design of the accompanying optical system. Variations in tilt angle within a device may result in apparent non-uniformities, such as line pairing and image mottling, across the projected image. Variations in the average tilt angle between devices may

result in colorimetry and system contrast variations. The specified limits represent the tolerances of the tilt angles within a device.

Note 2: DMD Efficiency

The overall DMD efficiency includes window transmittance, active area fill factor, active area mirror specular reflectivity, and diffraction efficiency. It is defined as that percentage of light incident upon the mirror array that is specularly reflected from the mirror array. The measurement is made with all mirrors in the full on-state without electronic duty cycle effects (i.e. measure using 100% duty cycle).

Note 3: Window Transmittance

Angle of incidence $0^\circ - 45^\circ$. Two AR coating surfaces at 0.5% reflectivity per AR coating.

Note 4: Visible window transmission below 420nm

Transmission not currently controlled below 420nm. Typical measurements at $0-26^\circ$ angle of incidence ranged from 95-98% @ 405nm to 70-85% @ 350nm.

Note 5: UV window transmission

Currently specified as an average measured at 0° angle of incidence only. Typical measurements at $0-26^\circ$ angle of incidence ranged from 98-99% @ 405nm to 97-99% @ 350nm.

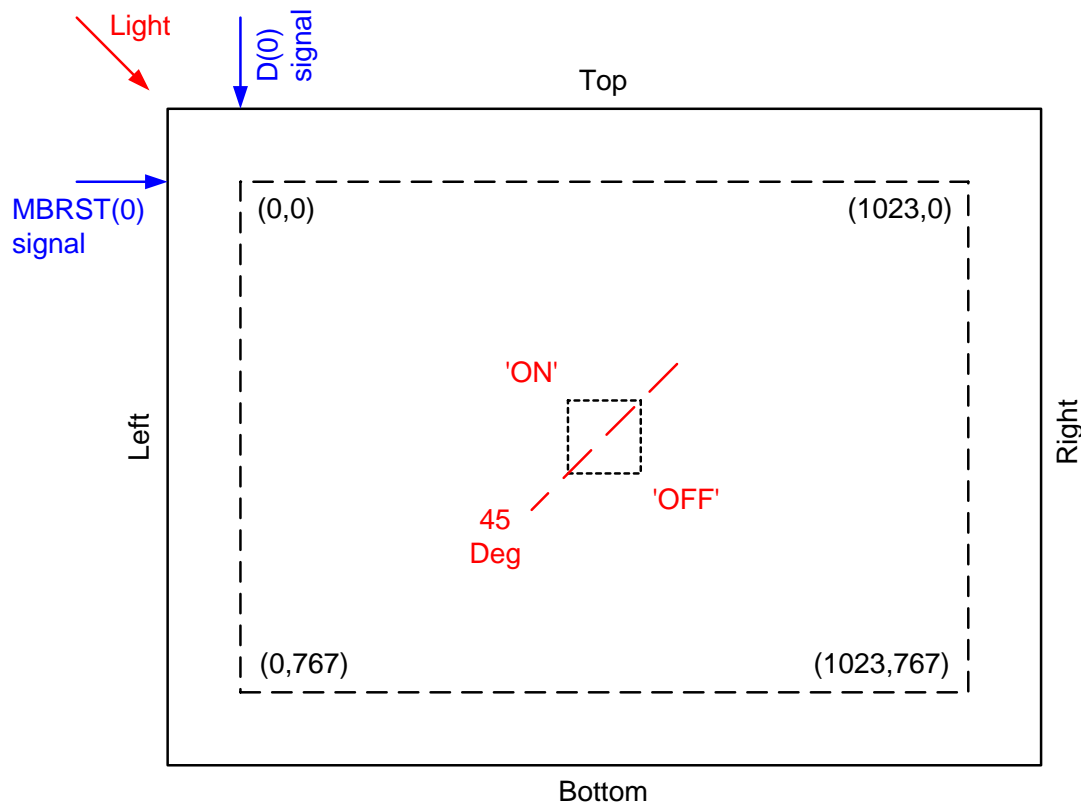


Figure 4. Mirror Tilt Axis Orientation

Table 11. Optical Interface and System Image Quality					
Parameter		Min	Nom	Max	Unit
	Note 1				

Note 1:

Optimizing system optical performance and image quality strongly relate to optical system design parameter trades. Although it is not possible to anticipate every conceivable application, projector image quality and optical performance is contingent on compliance to the optical system operating conditions described in a) through c) below:

a) Numerical Aperture and Stray Light Control.

The angle defined by the numerical aperture of the illumination and projection optics at the DMD optical area should be the same. This angle should not exceed the nominal device mirror tilt angle unless appropriate apertures are added in the illumination and/or projection pupils to block out flat-state and stray light from the projection lens. The mirror tilt angle defines DMD capability to separate the "ON" optical path from any other light path, including undesirable flat-state specular reflections from the DMD window, DMD border structures, or other system surfaces near the DMD such as prism or lens surfaces. If the numerical aperture exceeds the mirror tilt angle, or if the projection numerical aperture angle is more than two degrees larger than the illumination numerical aperture angle, objectionable artifacts in the display's border and/or active area could occur.

b) Pupil Match. TI's optical and image quality specifications assume that the exit pupil of the illumination optics is nominally centered within two degrees of the entrance pupil of the projection optics. Misalignment of pupils can create objectionable artifacts in the display's border and/or active area, which may require additional system apertures to control, especially if the numerical aperture of the system exceeds the pixel tilt angle.

c) Illumination Overfill. The active area of the device is surrounded by an aperture on the inside DMD window surface that masks undesirable structures of the DMD package from normal view, and is sized to anticipate several optical operating conditions. Overfill light illuminating the aperture can create artifacts from the edge of the window aperture coating and other surface anomalies that may be visible on the screen. The illumination optical system should be initially designed to limit light flux incident anywhere on the window aperture from exceeding approximately 10% of the average flux level in the active area. Depending on the particular system's optical architecture, overfill light may have to be further reduced below the suggested 10% level in order to be acceptable..

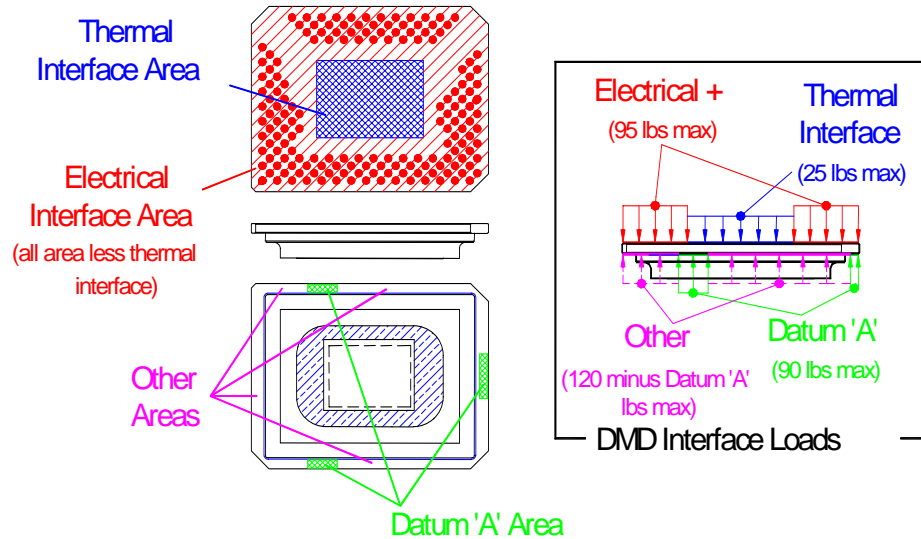
TI ASSUMES NO RESPONSIBILITY FOR IMAGE QUALITY ARTIFACTS OR DMD FAILURES CAUSED BY OPTICAL SYSTEM OPERATING CONDITIONS EXCEEDING LIMITS DESCRIBED ABOVE.

The DMD 0.7XGA 12° DDR is offered in a Type A package. Package mechanical dimensions and tolerances are shown in the DMD Mechanical ICD drawing referenced in Table 1.

Table 12. System Interface Parameters					
Parameter		Min	Nom	Max	Unit
Maximum Load to be Applied to the					
	• Thermal Interface area			25	lbs
	• Electrical Interface area			95	lbs
	• Datum "A" Interface area			90	lbs

Note 1:

Combined loads of the thermal and electrical interface areas in excess of the Datum "A" load shall be evenly distributed outside the Datum "A" area ($95 + 25 - \text{Datum "A"}$). Refer to Figure 5 for package interface load diagrams.



Thermal interface and Datum 'A' areas defined in the Mechanical ICD.

Figure 5. System Interface Loads

Table 13. Pad Coordinates vs Signal Name			
PAD #	SIGNAL NAME	PAD #	SIGNAL NAME
A01	D(10)	C25	D(42)
A03	D(23)	C27	D(52)
A05	VCC	C29	VSS (GND)
A07	D(24)	D02	VCC
A09	D(27)	D04	D(6)
A11	VCC	D06	D(12)
A13	D(30)	D08	VSS (GND)
A15	D(31)	D10	D(14)
A17	VCC	D12	D(25)
A19	D(34)	D14	VSS (GND)
A21	D(35)	D16	D(32)
A23	VCC	D18	D(37)
A25	D(40)	D20	VSS (GND)
A27	D(44)	D22	D(46)
A29	VCC	D24	D(56)
B02	VSS (GND)	D26	D(54)
B04	D(18)	D28	D(58)
B06	D(16)	D30	D(60)
B08	VSS (GND)	E01	D(0)
B10	D(26)	E03	D(1)
B12	D(28)	E05	D(2)
B14	VSS (GND)	E27	VSS (GND)
B16	CMD0	E29	VSS (GND)
B18	D(33)	F02	VSS (GND)
B20	VSS (GND)	F04	VSS (GND)
B22	D(38)	F26	D(63)
B24	D(39)	F28	D(62)
B26	VSS (GND)	F30	D(61)
B28	D(50)	G01	D(3)
B30	D(48)	G03	D(5)
C01	D(4)	G05	D(7)
C03	D(8)	G27	D(57)
C05	VSS (GND)	G29	D(59)
C07	D(22)	H02	D(9)
C09	D(20)	H04	D(11)
C11	VSS (GND)	H06	D(13)
C13	D(29)	H26	VSS (GND)
C15	DCLK	H28	VSS (GND)
C17	VSS (GND)	H30	VCC
C19	D(36)	J01	VCC
C21	D(41)	J03	VSS (GND)
C23	VSS (GND)	J05	VSS (GND)
J25	D(51)	Y16	MBRST(9)
J27	D(53)	Y18	VSS (GND)
J29	D(55)	Y20	MBRST(15)
K02	VSS (GND)	Y22	EVCC
K04	D(17)	Y24	VSS (GND)

Table 13. Pad Coordinates vs Signal Name			
PAD #	SIGNAL NAME	PAD #	SIGNAL NAME
K06	D(15)	AA07	VSS (GND)
K26	D(47)	AA09	VSS (GND)
K28	D(45)	AA11	MBRST(2)
K30	D(49)	AA13	MBRST(4)
L01	TRC	AA15	VSS (GND)
L03	D(21)	AA17	MBRST(11)
L05	D(19)	AA19	MBRST(13)
L25	VSS (GND)	AA21	VSS (GND)
L27	VSS (GND)	AA23	TP65
L29	VSS (GND)	AA25	CMD3
M02	VSS (GND)	AB06	VSS (GND)
M04	VSS (GND)	AB08	EVCC
M26	D(43)	AB10	MBRST(1)
M28	TP67	AB12	VSS (GND)
M30	VCC	AB14	MBRST(7)
N01	VCC	AB16	MBRST(8)
N03	CMD1	AB18	VSS (GND)
N27	VSS (GND)	AB20	MBRST(14)
N29	VCC2	AB22	TP66
P02	VCC2	AB24	VSS (GND)
P04	VSS (GND)	AB26	VSS (GND)
P28	VSS (GND)	AC05	VCC
P30	VCC2	AC07	VSS (GND)
R01	VCC2	AC09	VCC
R03	VSS (GND)	AC11	MBRST(3)
R29	VCC2	AC13	MBRST(5)
T02	VCC2	AC15	VCC
T28	VSS (GND)	AC17	MBRST(10)
T30	VCC2	AC19	MBRST(12)
U01	VCC2	AC21	VCC
U03	VSS (GND)	AC23	VSS (GND)
U29	VSS (GND)	AC25	CMD2
V02	VSS (GND)	AC27	VCC
V30	VCC		
W01	VCC		
Y08	VSS (GND)		
Y10	MBRST(0)		
Y12	VSS (GND)		
Y14	MBRST(6)		

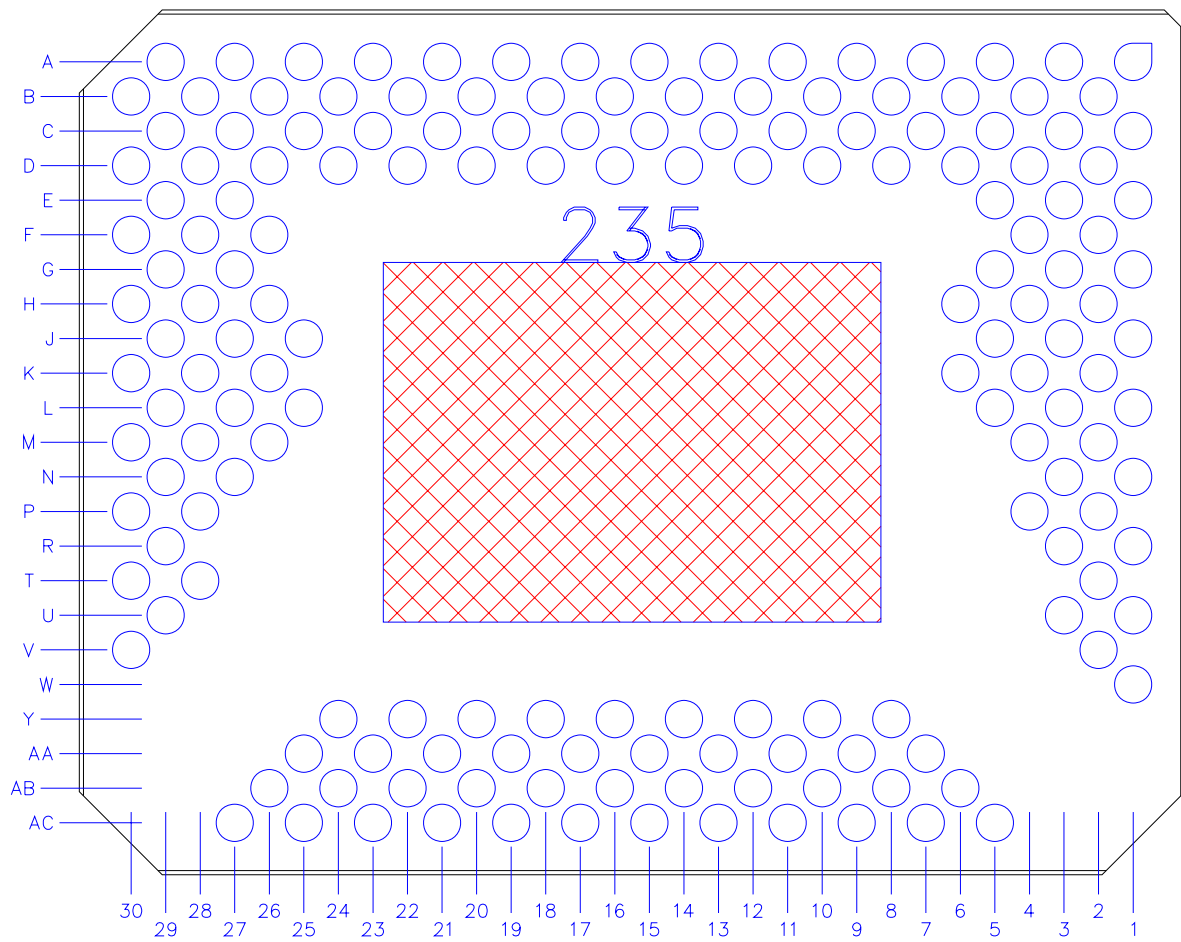


Figure 6. Package Back Pads

Electrostatic Discharge Immunity

All external signals on the DMD are protected from damage by electrostatic discharge, and are tested in accordance with JESD22-A114-B Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM).

Table 14. DMD ESD Protection Limits		
Package Pin Type	Voltage (maximum)	Units
Input	2000	V
Output	2000	V
Power	2000	V
MBRST(15:0)	< 250	V

Caution

MBRST(0:15) ESD input protection is limited to charge sharing between the ESD source and the intrinsic capacitance of the signal.

Please see Note 4 of Table 3 on VCC2 sensitivity.

Notes on Handling

All CMOS devices require proper ESD handling procedures. Refer to Drawing # 4144804 (DMD Handling & Cleaning Procedure) for static charge prevention, dust and dirt protection.